

SM712 Series 600W Asymmetrical TVS Diode Array







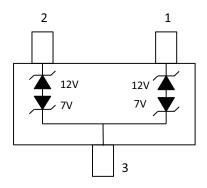


Description

The SM712 TVS Diode Array is designed to protect RS-485 applications with asymmetrical working voltages (-7V to 12V) from damage due to electrostatic discharge (ESD), electrical fast transients (EFT), and lightning induced surges.

The SM712 can absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard without performance degradation and safely dissipate up to 19A of 8/20us induced surge current (IEC-61000-4-5 2nd edition) with very low clamping voltages.

Pinout and Functional Block Diagram



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Additional Information









Features

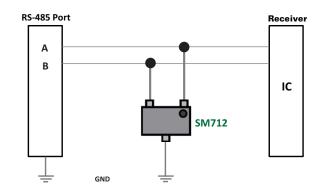
- RoHS compliant and lead-free
- ESD, IEC 61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC 61000-4-4, 50A (5/50ns)
- Lightning, IEC 61000-4-5 2nd edition, 19A $(t_p = 8/20 \mu s)$
- Working Voltages: -7V to 12V
- Low clamping voltage
- Low leakage current
- AEC-Q101 Qualified
- Moisture Sensitivity Level (MSL-1)

Applications

- RS-485
- Fieldbus
- Modbus
- Profibus
- DMX512

- Security Systems
- AutomatedT eller Machines (ATMs)
- Lighting Control DALI
- Communication Equipments

RS-485 Application Example



TVS Diode Arrays (SPA® Diodes)

General Purpose ESD Protection - SM712

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
P_{Pk}	Peak Pulse Power (t _p =8/20µs)	600	W
I _{PP}	Peak Pulse Current (t _p =8/20µs)	19	А
T _{OP}	Operating Temperature	-40 to 125	°C
T _{STOR}	Storage Temperature	-55 to 150	°C

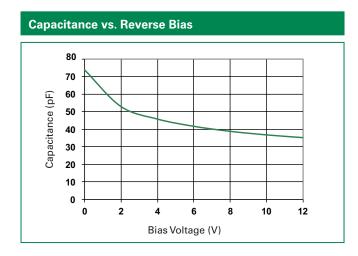
Notes:

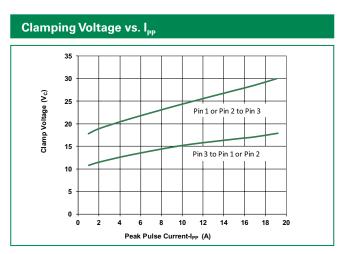
CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

SM712 Electrical Characteristics (T_{OP}=25°C)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V _{RWM}	I _R ≤1μA, Pin 3 to Pin 1 or Pin 2			7.0	V
		I _R ≤1μA, Pin 1 or Pin 2 to Pin 3			12.0	V
Reverse Breakdown Voltage	V _R	I _R =1mA, Pin 3 to Pin 1 or Pin 2	7.5			V
		I _R =1mA, Pin 1 or Pin 2 to Pin 3	13.3			V
Leakage Current	I _{LEAK}	V _R =7V			20	μΑ
		V _R =12V			1	μΑ
Clamp Voltage ¹	V _c	I_{pp} =1A, t_{p} =8/20µs, Pin 1 or Pin 2 to Pin 3			19	V
		I_{pp} =1A, t_p =8/20µs, Pin 3 to Pin 1 or Pin 2			11	V
		I_{pp} =19A, t_p =8/20µs, Pin 1 or Pin 2 to Pin 3			31	V
		I_{pp} =19A, t_p =8/20µs, Pin 3 to Pin 1 or Pin 2			19	V
Dynamic Resistance ¹	R _{DYN}	$(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$		0.5		Ω
ESD Withstand Voltage ¹	V _{ESD}	IEC 61000-4-2 (Contact Discharge)	±30			kV
		IEC 61000-4-2 (Air Discharge)	±30			kV
Diode Capacitance ¹ C _{I/O-GND}		Reverse Bias=0V, f=1MHz; Pin 1 or Pin 2 to Pin 3			75	pF

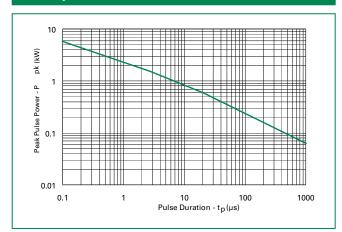
Notes: 1. Parameter is guaranteed by design and/or device characterization.

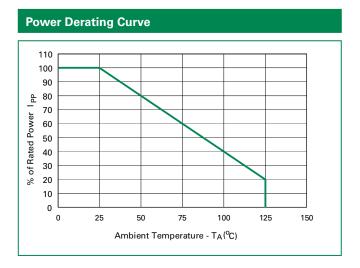




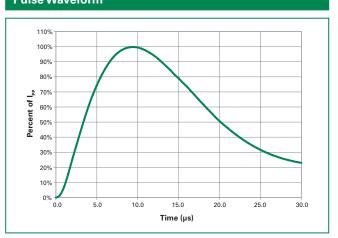


Non-Repetitive Peak Pulse Power vs. Pulse Time



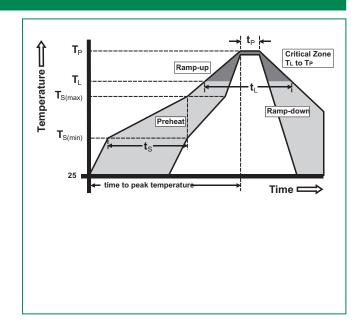


Pulse Waveform



Soldering Parameters

Reflow Condition		Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ra to peak	mp up rate (Liquidus) Temp (T _L)	3°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		3°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
nellow	-Temperature (t _L)	60 - 150 seconds	
Peak Temp	erature (T _P)	260+0/-5 °C	
Time within 5°C of actual peak Temperature (t _p)		20 - 40 seconds	
Ramp-down Rate		6°C/second max	
Time 25°C to peak Temperature (T _p)		8 minutes Max.	
Do not exc	eed	260°C	



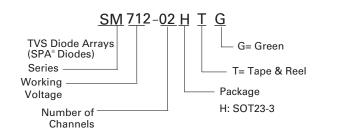


Part Marking System 712

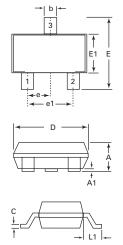
Ordering Information

Part Number	Package	Marking	Min. Order Qty.
SM712-02HTG	SOT23-3	712	3000

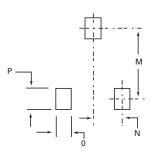
Part Numbering System



Package Dimensions — SOT23-3



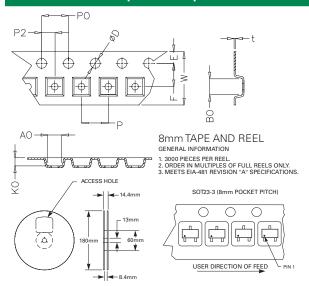
Recommended Pad Layout



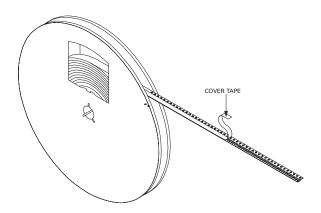
Package	SOT23-3				
Pins	3				
JEDEC	TO-236				
	Millimeters		Inches		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A1	0.01	0.1	0.0004	0.004	
b	0.3	0.5	0.012	0.020	
С	0.08	0.2	0.003	0.008	
D	2.8	3.04	0.110	0.120	
Е	2.1	2.64	0.083	0.104	
E1	1.2	1.4	0.047	0.055	
е	0.95 BSC		0.038 BSC		
e1	1.90 BSC		0.075 BSC		
L1	0.54 REF		0.021 REF		
M	_	2.29	_	.090	
N	_	0.95	_	0.038	
0	-	0.78	-	.030TYP	
Р	-	0.78	030TYP		



Embossed Carrier Tape & Reel Specification — SOT23-3



Symbol	Millimetres		Inches		
	Min	Max	Min	Max	
E	1.65	1.85	0.065	0.073	
F	3.40	3.60	0.134	0.142	
P2	1.90	2.10	0.075	0.083	
D	1.40	1.60	0.055	0.063	
P0	3.90	4.10	0.154	0.161	
W	7.70	8.30	0.303	0.327	
Р	3.90	4.10	0.154	0.161	
Α0	3.05	3.25	0.120	0.128	
В0	2.67	2.87	0.105	0.113	
K0	1.12	1.32	0.044	0.052	
t	0.22	0.24	0.009	0.009	



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